



40V P-CHANNEL ENHANCEMENT MODE MOSFET PowerDI5060-8

Product Summary

BV _{DSS}	Rds(on) max	I _D Tc = +25°C
-40V	5.2mΩ @ V _{GS} = -10V	-115A
-400	7.9mΩ @ V _{GS} = -6V	-94A

Description and Applications

This new generation MOSFET has been designed to minimize the onstate resistance (RDS(ON)) yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- Reverse Polarity Protection
- BLDC Motor Control
- Power Management Functions
- System/Load Switch

Features and Benefits

- 100% Unclamped Inductive Switch (UIS) Test in Production
- Low On-Resistance
- Fast Switching Speed
- Wettable Flank for Improved Optical Inspections
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e.: parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please refer to the related automotive grade (Q-suffix) part. A listing can be found at

https://www.diodes.com/products/automotive/automotive-products/.

 This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.

https://www.diodes.com/quality/product-definitions/

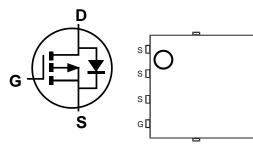
Mechanical Data

- Case: PowerDI[®]5060-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish Matte Tin Annealed over Copper Leadframe;
 Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.097 grams (Approximate)

PowerDI5060-8 (SWP) (Type UX)



Top View Bottom View



Internal Schematic Top View Pin Configuration

Ordering Information (Note 4)

Part Number	Case	Packaging
DMP4006SPSW-13	PowerDI5060-8 (SWP) (Type UX)	2,500 / Tape & Reel

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

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Marking Information



YY= Year (ex: 21 = 2021) WW = Week (01 to 53)

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage	V_{DSS}	-40	V		
Gate-Source Voltage	V_{GSS}	±20	V		
Continuous Drain Current (Note 6) V _{GS} = -10V	I _D	-115 -92	А		
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	I _{DM}	-460	Α		
Maximum Body Diode Continuous Current	Is	-115	А		
Pulsed Source Current (10µs Pulse, Duty Cycle = 1%)			lsм	-460	Α
Avalanche Current (L =0.1mH)			IAS	-72	Α
Avalanche Energy (L = 0.1mH)			E _{AS}	262	mJ

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)	$T_A = +25^{\circ}C$	P_{D}	3.4	W
Thermal Resistance, Junction to Ambient (Note 5) Steady State		Reja	36.5	°C/W
Total Power Dissipation (Note 6) $T_C = +25^{\circ}C$		PD	104	W
Thermal Resistance, Junction to Case (Note 6)	Reлc	1.2	°C/W	
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C	

5. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate. 6. Thermal resistance from junction to soldering point (on the exposed drain pad). Notes:



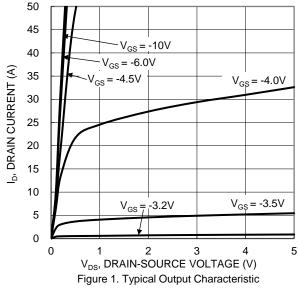
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

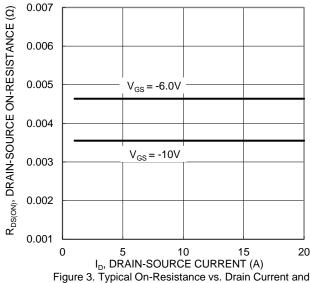
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BVDSS	-40	_	_	٧	$V_{GS} = 0V, I_{D} = -250\mu A$	
Zero Gate Voltage Drain Current	IDSS		_	-1	μΑ	$V_{DS} = -40V$, $V_{GS} = 0V$	
Gate-Source Leakage	IGSS		_	±100	nA	$V_{GS} = \pm 20V$, $V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	Vgs(th)	-2.0	_	-3.0	V	$V_{DS} = V_{GS}$, $I_D = -250\mu A$	
Static Drain-Source On-Resistance	Pro/our		3.6	5.2	mΩ	$V_{GS} = -10V, I_{D} = -9.8A$	
Static Diain-Source On-Resistance	RDS(ON)		4.5	7.9	1112.2	$V_{GS} = -6V, I_{D} = -9.8A$	
Diode Forward Voltage	V_{SD}		-0.7	-1	V	$V_{GS} = 0V$, $I_S = -1A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss		6855	_		V _{DS} = -20V, V _{GS} = 0V f = 1MHz	
Output Capacitance	Coss	_	883	_	pF		
Reverse Transfer Capacitance	Crss	_	526	_			
Gate Resistance	Rg	_	7.8	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge (V _{GS} = -10V)	Qg		162	_			
Gate-Source Charge	Qgs		28	_	nC	$V_{DS} = -20V, I_{D} = -9.8A$	
Gate-Drain Charge	Q_{gd}	_	38	_			
Turn-On Delay Time	td(ON)	_	28	_			
Turn-On Rise Time	tR	_	32	_		$V_{GS} = -10V$, $V_{DD} = -20V$, $R_{G} = 6\Omega$, $I_{D} = -9.8A$	
Turn-Off Delay Time	tD(OFF)		469	_	ns		
Turn-Off Fall Time	tF	_	228	_			
Reverse Recovery Time	t _{RR}		44	_	ns	I _F = -9.8A, di/dt = -100A/µs	
Reverse Recovery Charge	Q _{RR}		48	_	nC	IF = -9.8A, di/dt = -100A/µs	

Notes: 7. Short duration pulse test used to minimize self-heating effect.

^{8.} Guaranteed by design. Not subject to product testing.







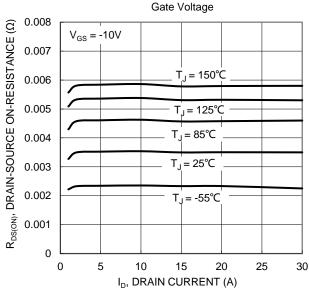
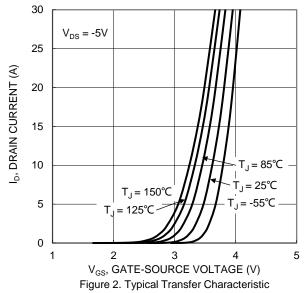
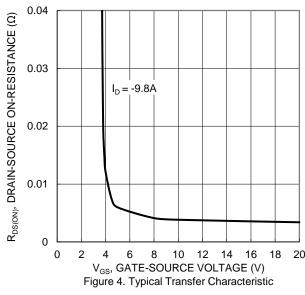


Figure 5. Typical On-Resistance vs. Drain Current and Junction Temperature





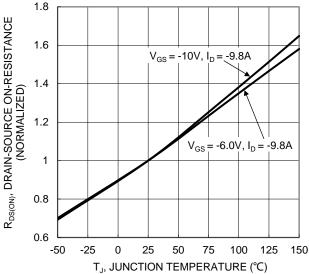


Figure 6. On-Resistance Variation with Junction Temperature



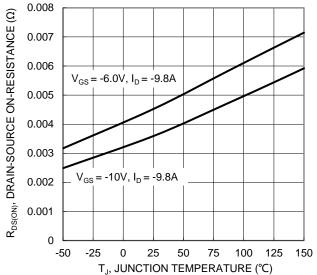
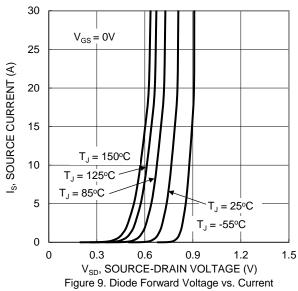


Figure 7. On-Resistance Variation with Junction Temperature



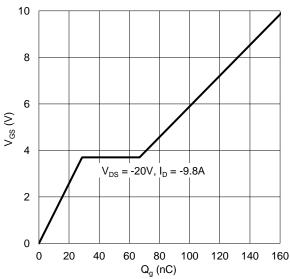
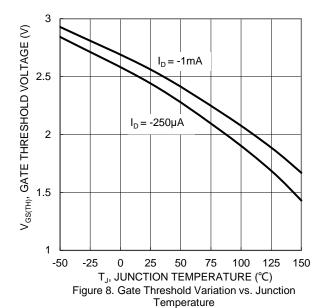
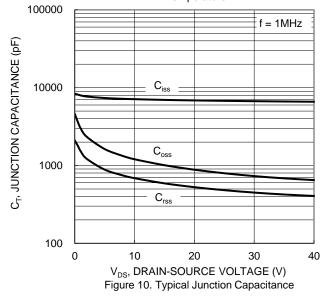
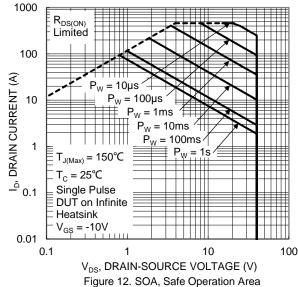


Figure 11. Gate Charge









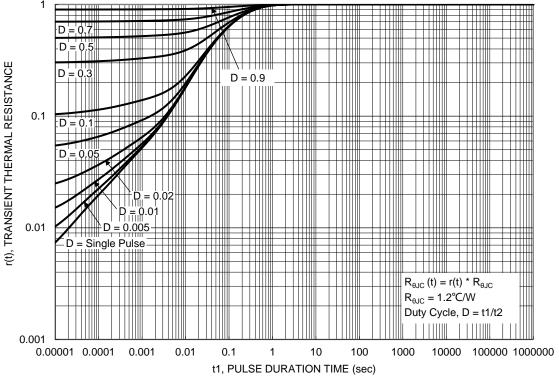


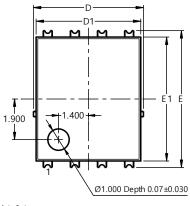
Figure 13. Transient Thermal Resistance

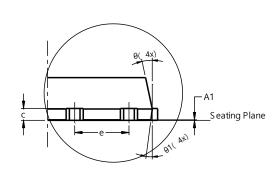


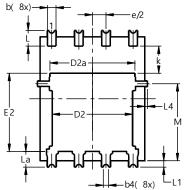
Package Outline Dimensions

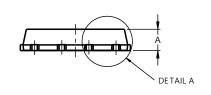
Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8 (SWP) (Type UX)









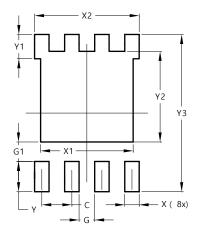
DETAIL A

PowerDI5060-8 (SWP) (Type UX)					
Dim	Min	Max	Тур		
Α	0.90	1.10	1.00		
A1	0	0.05			
b	0.30	0.50	0.41		
b2	0.20	0.35	0.25		
b4	0.25REF				
С	0.230	0.330	0.277		
D		.15 BS0	2		
D1	4.70	5.10	4.90		
D2	3.56	3.96	3.76		
D2a	3.78 4.18 3.9		3.98		
Е	6.40 BSC				
E1	5.60	6.00	5.80		
E2	3.46	3.86	3.66		
E2a	4.195	4.595	4.395		
е	1.27BSC				
k	1.05				
L	0.635	0.835	0.735		
La	0.635	0.835	0.735		
L1	0.200	0.400	0.300		
L1a	0.050REF				
L4	0.025	0.225	0.125		
M	3.205	4.005	3.605		
θ	10°	12°	11°		
θ1	0 0 1		7°		
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8 (SWP) (Type UX)



Dimensions	Value		
Dillielisions	(in mm)		
С	1.270		
G	0.660		
G1	0.820		
X	0.610		
X1	4.100		
X2	4.420		
Υ	1.270		
Y1	1.020		
Y2	3.810		
Y3	6.610		



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